

Complementary power transistors

Features

- Complementary PNP-NPN devices
- New enhanced series
- High switching speed
- h_{FE} grouping
- h_{FE} improved linearity

Applications

- General purpose circuits
- Audio amplifier
- Power linear and switching

Description

The TIP41C is a base island technology NPN power transistor in TO-220 plastic package that make this device suitable for audio, power linear and switching applications. The complementary PNP type is TIP42C

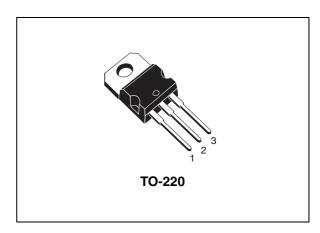


Figure 1. Internal schematic diagram

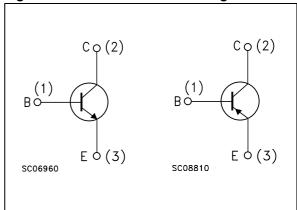


Table 1. Device summary

Order code Marking		Package	Packaging
TIP41C (Note 1 on page 4)	TIP41C R TIP41C O TIP41C Y	TO-220	Tube
TIP42C (Note 1 on page 4)	TIP42C R TIP42C O TIP42C Y	TO-220	Tube

Contents TIP41C - TIP42C

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1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	100	V
V _{EBO}	Emitte-base voltage (I _C = 0)	5	V
I _C	Collector current	6	Α
I _{CM}	Collector peak current (t _P < 5ms)	10	Α
I _B	Base current	3	Α
P _{TOT}	Total dissipation at T _{case} = 25°C	65	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative

Electrical characteristics TIP41C - TIP42C

2 Electrical characteristics

(T_{case} = 25°C; unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test con	Min.	Тур.	Max.	Unit	
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 60 V				0.7	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V				1	mA
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 100 V				0.4	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30 mA		100			٧
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 6 A	$I_{B} = 0.6 A$			1.5	V
V _{BE(on)} ⁽¹⁾	Base-emitter voltage	I _C = 6 A	$V_{CE} = 4 V$			2	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 0.3 A$ $I_C = 3 A$ Group R Group O Group Y	~ —	30 15 15 24 42		75 28 44 75	

^{1.} Pulsed duration = 300 ms, duty cycle \geq 1.5%.

Note: 1 Product is pre-selected in DC current gain (group R, group O and group Y).

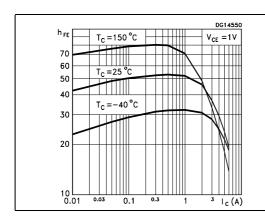
STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

Note: For PNP types voltage e current values are negative.

2.1 Typical characteristic (curves)

Figure 2. DC current gain (NPN)

Figure 3. DC current gain (PNP)



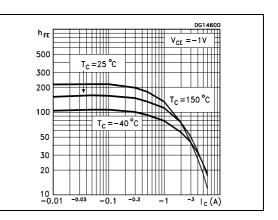
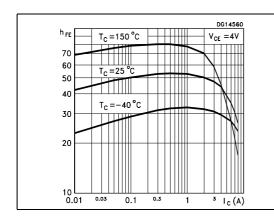


Figure 4. DC current gain (NPN)

Figure 5. DC current gain (PNP)



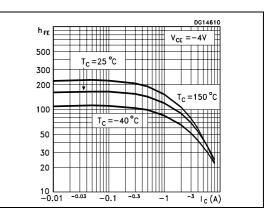
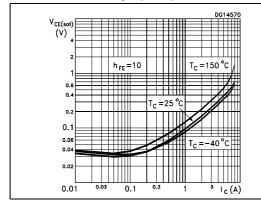
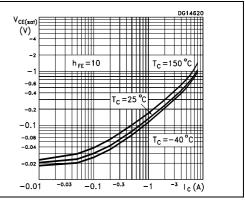


Figure 6. Collector-emitter saturation voltage (NPN)

Figure 7. Collector-emitter saturation voltage (PNP)

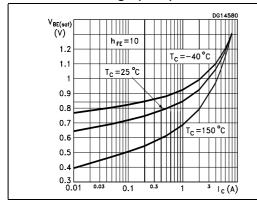




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Figure 8. Base-emitter saturation voltage (NPN)

Figure 9. Base-emitter saturation voltage (PNP)



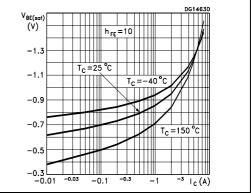
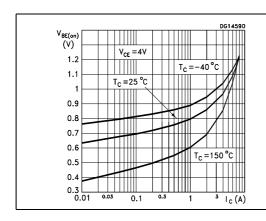


Figure 10. Base-emitter voltage (NPN)

Figure 11. Base-emitter voltage (PNP)



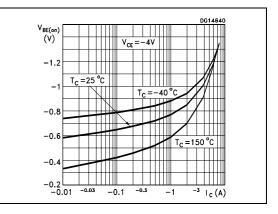
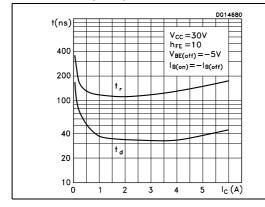
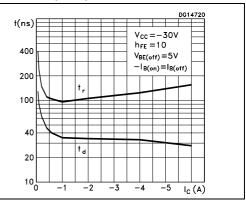


Figure 12. Resistive load switching time Figure 13. Resistive load switching time (NPN) (PNP)





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Figure 14. Resistive load switching time Figure 15. Resistive load switching time (NPN) (PNP)

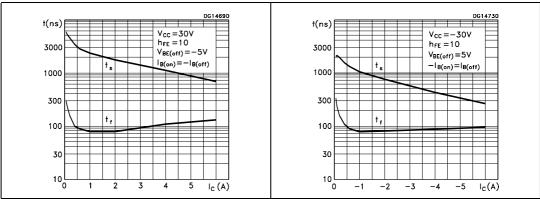
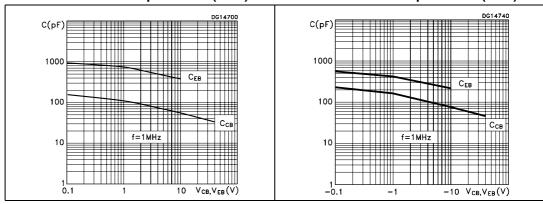


Figure 16. Collector-base and collector- Figure 17. Collector-base and collector- emitter capacitance (NPN) emitter capacitance (PNP)



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2.2 Test circuit

Figure 18. Inductive load switching test circuit

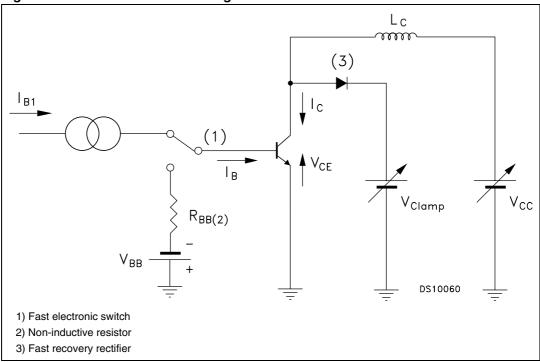
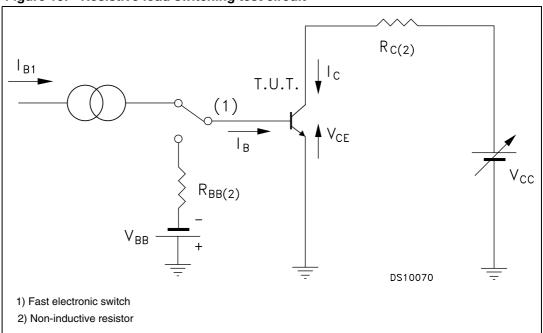


Figure 19. Resistive load switching test circuit



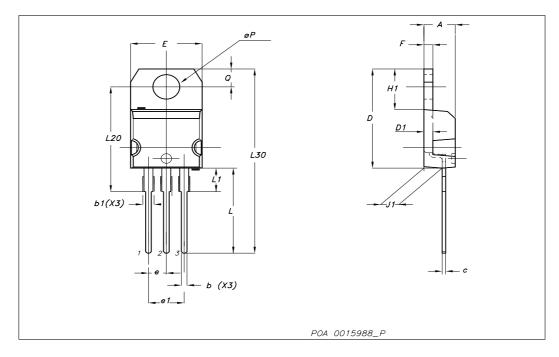
Note: For PNP types voltage e current values are negative.

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 mechanical data

Dim		mm			inch			
	Min	Тур	Max	Min	Тур	Max		
Α	4.40		4.60	0.173		0.181		
b	0.61		0.88	0.024		0.034		
b1	1.14		1.70	0.044		0.066		
С	0.49		0.70	0.019		0.027		
D	15.25		15.75	0.6		0.62		
D1		1.27			0.050			
Е	10		10.40	0.393		0.409		
е	2.40		2.70	0.094		0.106		
e1	4.95		5.15	0.194		0.202		
F	1.23		1.32	0.048		0.051		
H1	6.20		6.60	0.244		0.256		
J1	2.40		2.72	0.094		0.107		
L	13		14	0.511		0.551		
L1	3.50		3.93	0.137		0.154		
L20		16.40			0.645			
L30		28.90			1.137			
ØP	3.75		3.85	0.147		0.151		
Q	2.65		2.95	0.104		0.116		



TIP41C - TIP42C Revision history

4 Revision history

Table 4. Document revision history

Date	Revision	Changes	
24-Oct-2006	1	Initial release	
19-Nov-2007	2	Content reworked to improve readability, no technical changes	

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